

# NPN SILICON PLANAR SWITCHING TRANSISTORS

#### 2N2221 2N2222

СВЕ

TO-18 Metal Can Package

#### Switching and Linear Application DC and VHF Amplifier Applications

#### ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	2N2221, 22	UNIT
Collector Emitter Voltage	V <sub>CEO</sub>	30	V
Collector Base Voltage	V <sub>CBO</sub>	60	V
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current Continuous	Ι <sub>C</sub>	800	mA
Power Dissipation @Ta=25°C	P <sub>D</sub>	500	mW
Derate Above 25°C		2.28	mW/ºC
Power Dissipation @ Tc=25°C	P <sub>D</sub>	1.2	W
Derate Above 25°C		6.85	mW/ºC
Operating and Storage Junction	T <sub>j</sub> , T <sub>stg</sub>	-65 to +200	O°
Temperature Range			

#### ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise )

DESCRIPTION	SYMBOL	TEST CONDITION	VALUE		
			MIN	MAX	UNIT
Collector Emitter Breakdown Voltage	$BV_{CEO}$	I <sub>C</sub> =10mA,I <sub>B</sub> =0	30		V
Collector Base Breakdown Voltage	$BV_{CBO}$	I <sub>C</sub> =10μΑ.Ι <sub>Ε</sub> =0	60		V
Emitter Base Breakdown Voltage	$BV_{EBOf}$	I <sub>E</sub> =10μΑ, I <sub>C</sub> =0	5		V
Collector Leakage Current	$I_{CBO}$	$V_{CB}$ =50V, I <sub>E</sub> =0		10	nA
		V <sub>CB</sub> =50V, I <sub>E</sub> =0		10	μA
		Ta=150 ° C			
Collector Emitter Saturation Voltage	V <sub>CE(Sat)</sub> *	I <sub>C</sub> =150mA,I <sub>B</sub> =15mA		0.4	V
		I <sub>C</sub> =500mA,I <sub>B</sub> =50mA		1.6	V
Base Emitter Saturation Voltage	V <sub>BE(Sat)</sub> *	I <sub>C</sub> =150mA,I <sub>B</sub> =15mA	0.6	1.3	V
		I <sub>C</sub> =500mA,I <sub>B</sub> =50mA		2.6	V

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ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise	<b>)</b> )
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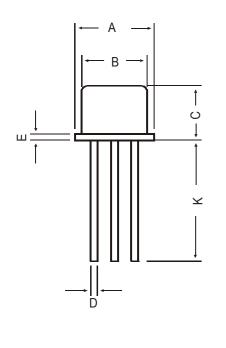
DESCRIPTION	SYMBOL	. TEST CONDITION	2221		2222		UNIT
			MIN	MAX	MIN	MAX	
DC Current Gain	h <sub>FE</sub>	I <sub>C</sub> =0.1mA,V <sub>CE</sub> =10V*	20		35		
		I <sub>C</sub> =1mA,V <sub>CE</sub> =10V	25		50		
		I <sub>C</sub> =10mA,V <sub>CE</sub> =10V*	35		75		
		I <sub>C</sub> =150mA,V <sub>CE</sub> =1V*	20		50		
		I <sub>C</sub> =150mA,V <sub>CE</sub> =1V*	40	120	100	300	
		I <sub>C</sub> =500mA,V <sub>CE</sub> =10V*	20		30		
DYNAMIC CHARACTERISTICS							
Transition Frequency	f⊤	I <sub>C</sub> =20mA, V <sub>CE</sub> =20V	250		250		MHz
		f=100MHz					
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0		8		8	pF
		f=100KHz					
Input Capacitance	C <sub>ib</sub>	V <sub>FB</sub> =0.5V, I <sub>C</sub> =0		30		30	pF
		f=100kHz					·
SWITCHING CHARACTERISTICS							
Delay time	t <sub>d</sub>					10	ns
		I <sub>C</sub> =150mA,IB1=15mA					
Rise time	t <sub>r</sub>	V <sub>CC</sub> =30V,V <sub>BE(off)</sub> =0.5V				25	ns
Storage time	t <sub>s</sub>					225	ns
-	-	I <sub>C</sub> =150mA, IB1=15mA					
Fall time	t <sub>f</sub>	IB2=15mA, V <sub>CC</sub> =30V				60	ns

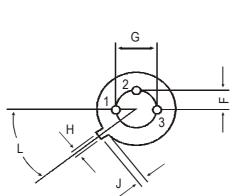
\*Pulse Condition: Pulse Width <300µs, Duty Cycle <2%

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## **TO-18 Metal Can Package**





	DIM	MIN	MAX
	А	5.24	5.84
	В	4.52	4.97
	С	4.31	5.33
	D	0.40	0.53
	Е		0.76
JM.	F	_	1.27
in n	G		2.97
SUC	Н	0.91	1.17
All diminsions in mm.	J	0.71	1.21
dimi	Κ	12.70	_
All o	L	45 E	DEG



PIN CONFIGURATION 1. EMITTER 2. BASE 3. COLLECTOR

# **Packing Detail**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
T0-18	1K/polybag	350 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	34 kgs

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#### Disclaimer

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CDIL is a registered Trademark of Continental Device India Limited C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290 e-mail sales@cdil.com www.cdil.com